

Low Voltage Octal Latch with 3-STATE Outputs

74LVX573

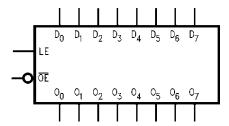
General Description

The LVX573 is a high-speed octal latch with buffered common Latch Enable (LE) and buffered common Output Enable (\overline{OE}) inputs. The LVX573 is functionally identical to the LVX373 but with inputs and outputs on opposite sides of the package. The inputs tolerate up to 5.5 V allowing interface of 5 V systems to 3 V systems.

Features

- Input Voltage Translation from 5 V to 3 V
- Ideal for Low Power / Low Noise 3.3 V Applications
- Guaranteed Simultaneous Switching Noise Level and Dynamic Threshold Performance
- This is a Pb-Free Device

Logic Symbol



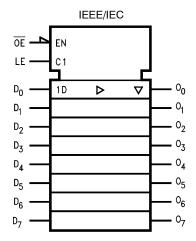


Figure 1. Logic Symbol



TSSOP20, 4.4x6.5 CASE 948AQ

MARKING DIAGRAM

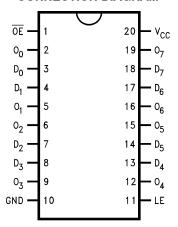


XXXXXX = Specific Device Code A = Assembly Location

L = Wafer Lot Y = Year W = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

CONNECTION DIAGRAM



PIN DESCRIPTION

	Pin Names	Description
	$D_0 - D_7$	Data Inputs
Ī	LE	Latch Enable Input
	ŌĒ	Output Enable Input
	O ₀ – O ₇	3-STATE Outputs

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Functional Description

The LVX573 contains eight D-type latches. When the enable (LE) input is HIGH, data on the Dn inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the informa-tion that was present on the D inputs a setup time preced-ing the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{\text{OE}}$) input. When $\overline{\text{OE}}$ is LOW, the buffers are enabled. When $\overline{\text{OE}}$ is HIGH the buffers are in the high impedance mode but this does not interfere with entering new data into the latches.

TRUTH TABLE

	Outputs		
ŌĒ	LE	D	O _n
L	Н	Н	Н
L	Н	L	L
L	L	Х	O ₀
Н	Х	Х	Z

H = HIGH Voltage

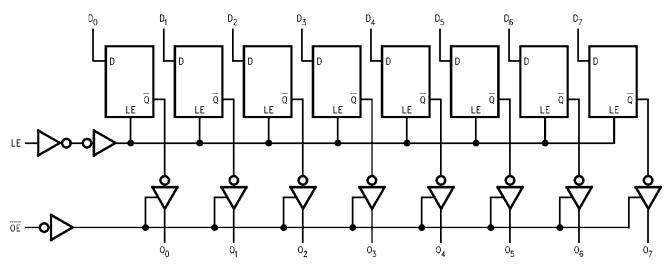
L = LOW Voltage

Z = High Impedance

X = Immaterial

O₀ = Previous O₀ before HIGH-to-LOW transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Figure 2. Logic Diagram

MAXIMUM RATINGS

Symbol	Pa	Value	Unit				
V _{CC}	DC Supply Voltage	-0.5 to +6.5	V				
V _{IN}	DC Input Voltage	-0.5 to +6.5	V				
V _{OUT}	DC Output Voltage	DC Output Voltage					
I _{IN}	DC Input Current, per Pin		±20	mA			
I _{OUT}	DC Output Current, per Pin		±25	mA			
I _{CC}	DC Supply Current, V _{CC} and GND Pins		±75	mA			
I _{IK}	Input Clamp Current	-20	mA				
lok	Output Clamp Current	±20	mA				
T _{STG}	Storage Temperature Range	-65 to +150	°C				
TL	Lead Temperature, 1 mm from Case for	260	°C				
TJ	Junction Temperature Under Bias		+150	°C			
$\theta_{\sf JA}$	Thermal Resistance (Note 2)	SOIC-20W	96	°C/W			
		TSSOP-20	150	1			
P_{D}	Power Dissipation in Still Air at 25 °C	SOIC-20W	1302	mW			
		TSSOP-20	833	1			
MSL	Moisture Sensitivity	SOIC-20W	Level 3	_			
		All Other Packages	Level 1				
F _R	Flammability Rating Oxygen Index: 28 to 34		UL 94 V-0 @ 0.573 in	-			
V _{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model	2000	V			
		Charged Device Model	N/A				

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Applicable to devices with outputs that may be tri-stated.
- 2. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
- 3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage	2.0	3.6	V
V _{IN}	DC Input Voltage (Note 4)	0	5.5	V
V _{OUT}	DC Output Voltage (Note 4)	0	V _{CC}	V
T _A	Operating Temperature	-40	+85	°C
t _r , t _f	Input Rise or Fall Rate	0	100	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS

						T _A = 25 °C		T _A = -40 °C	C to +85 °C		
Symbol	Parameter	Con	ditions	V _{CC}	Min	Тур	Max	Min	Max	Unit	
V _{IH}	HIGH Level			2.0	1.5	-	-	1.5	-	V	
	Input Voltage			3.0	2.0	_	-	2.0	-		
				3.6	2.4	-	-	2.4	-		
V _{IL}	LOW Level			2.0	-	-	0.5	-	0.5	V	
	input voitage	nput Voltage		3.0	-	-	0.8	-	0.8		
				3.6	ı	-	0.8	-	0.8		
V _{OH}	HIGH Level Output Voltage		V _{IN} = V _{IH} or V _{II}	$I_{OH} = -50 \mu A$	2.0	1.9	2.0	-	1.9	-	V
		O VIL	$I_{OH} = -50 \mu A$	3.0	2.9	3.0	-	2.9	_		
			$I_{OH} = -4 \text{ mA}$	3.0	2.58	-	-	2.48	-		
V _{OL}	LOW Level	$V_{IN} = V_{IH}$	I _{OL} = 50 μA	2.0	ı	0.0	0.1	-	0.1	V	
	Output Voltage	or V _{IL}	I _{OL} = 50 μA	3.0	ı	0.0	0.1	-	0.1		
			I _{OL} = 4 mA	3.0	ı	-	0.36	-	0.44		
l _{OZ}	3-STATE Output Off-State Current	$V_{IN} = V_{IH} C$ $V_{OUT} = V_{C}$		3.6	-	-	±0.25	-	±2.5	μΑ	
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V or GND		3.6	-	-	±0.1	_	±1.0	μΑ	
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$	or GND	3.6	-	-	4.0	_	40.0	μΑ	

NOISE CHARACTERISTICS (Note 5)

				T _A = 25 °C		
Symbol	Parameter	C _L (pF)	V _{CC} (V)	Тур	Limits	Unit
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	50	3.3	0.5	0.8	V
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	50	3.3	-0.5	-0.8	٧
V _{IHD}	Minimum HIGH Level Dynamic Input Voltage	50	3.3	-	2.0	٧
V_{ILD}	Maximum LOW Level Dynamic Input Voltage	50	3.3	-	0.8	V

^{5. (}Input $t_r = t_f = 3 \text{ ns}$)

AC ELECTRICAL CHARACTERISTICS

					T _A = 25 °C		T _A = -40 °C	C to +85 °C	
Symbol	Parameter	Conditions	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
t _{PLH} ,	Propagation Delay Time	C _L = 15 pF	2.7	_	7.6	14.5	1.0	17.5	ns
t _{PHL}	$(D_n \text{ to } O_n)$	C _L = 50 pF]	-	10.1	18.0	1.0	21.0	
		C _L = 15 pF	3.3 ±0.3	-	5.9	9.3	1.0	11.0	ns
		C _L = 50 pF]	-	8.4	12.8	1.0	14.5	
tPLH,	Propagation Delay Time	C _L = 15 pF	2.7	-	8.2	15.6	1.0	18.5	ns
t _{PHL}	(LE to O _n)	C _L = 50 pF]	-	10.7	19.1	1.0	22.0	
		C _L = 15 pF	3.3 ±0.3	-	6.4	10.1	1.0	12.0	
		C _L = 50 pF]	-	8.9	13.6	1.0	15.5	
t _{PZL} , t _{PZH}	3-STATE Output Enable Time	C_L = 15 pF, R_L = 1 k Ω	2.7	-	7.8	15.0	1.0	18.5	ns
		$C_L = 50 \text{ pF}$ $R_L = 1 \text{ k}\Omega$		-	10.3	18.5	1.0	22.0	
		C_L = 15 pF R_L = 1 k Ω	3.3 ±0.3	-	6.1	9.7	1.0	12.0	ns
		$C_L = 50 \text{ pF}$ $R_L = 1 \text{ k}\Omega$		-	8.6	13.2	1.0	15.5	
t _{PLZ} , t _{PHZ}	3-STATE Output Disable Time	C_L = 50 pF R_L = 1 k Ω	2.7	-	12.1	19.1	1.0	22.0	ns
		$C_L = 50 \text{ pF}$ $R_L = 1 \text{ k}\Omega$	3.3 ±0.3	-	10.1	13.6	1.0	15.5	
t _W	LE Pulse Width		2.7	6.5	-	-	7.5	_	ns
			3.3 ±0.3	5.0	-	-	5.0	_	
t _S	Setup Time		2.7	5.0	-	-	5.0	_	ns
	(D _n to LE)		3.3 ±0.3	3.5	-	_	3.5	_	
t _H	Hold Time		2.7	1.5	-	_	1.5	_	ns
	(D _n to LE)		3.3 ±0.3	1.5	-	-	1.5	_	
tosch,	Output to Output Skew (Note 6)	C _L = 50 pF	2.7	-	_	1.5	-	1.5	ns
toshl	Over (More o)		2.3	-	-	1.5	_	1.5	

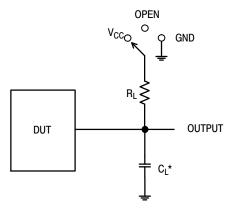
^{6.} Parameter guaranteed by design. $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$; $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

CAPACITANCE

		T _A = 25 °C		T _A = -40 °C to +85 °C			
Symbol	Parameter	Min	Тур	Max	Min	Max	Unit
C _{IN}	Input Capacitance	-	4	10	_	10	pF
C _{OUT}	Output Capacitance	-	6	-	_	-	pF
C _{PD}	Power Dissipation Capacitance (Note 7)	-	27	-	-	_	pF

^{7.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} · V_{CC} · f_{IN} + I_{CC} / 8 (per Latch).

TEST CIRCUITS



Test	Switch Position	C _L	R_{L}
t _{PLH} / t _{PHL}	Open	See AC	1 kΩ
t _{PLZ} / t _{PZL}	V _{CC}	Characteristics Table	
t _{PHZ} / t _{PZH}	GND		

Figure 3. AC Test Circuit

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
74LVX573MTCX	LVX 573	TSSOP-20	2500 Units / Tape & Reel

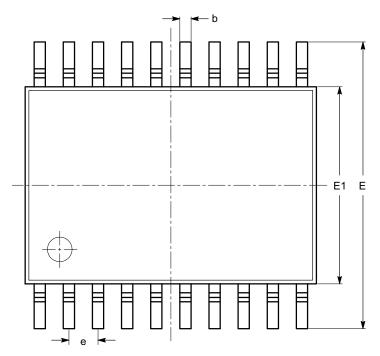
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}CL includes probe and jig capacitance Input $t_R = t_F = 3 \text{ ns}$



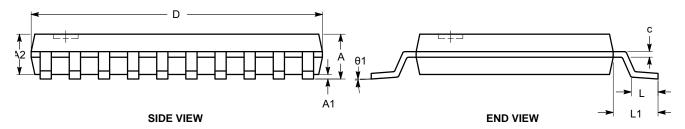
TSSOP20, 4.4x6.5 CASE 948AQ ISSUE A

DATE 19 MAR 2009



SYMBOL	MIN	NOM	MAX
А			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
С	0.09		0.20
D	6.40	6.50	6.60
Е	6.30	6.40	6.50
E1	4.30	4.40	4.50
е		0.65 BSC	
L	0.45	0.60	0.75
L1		1.00 REF	
θ	0°		8°

TOP VIEW



Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-153.

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